

# PDTC123Y series

NPN resistor-equipped transistors; R1 = 2.2 kΩ, R2 = 10 kΩ

Rev. 04 — 16 November 2009

Product data sheet

## 1. Product profile

### 1.1 General description

NPN Resistor-Equipped Transistors (RET) family.

Table 1. Product overview

Type number	Package			PNP complement
	NXP	JEITA	JEDEC	
PDTC123YE	SOT416	SC-75	-	PDTA123YE
PDTC123YK	SOT346	SC-59A	TO-236	PDTA123YK
PDTC123YM	SOT883	SC-101	-	PDTA123YM
PDTC123YS <sup>[1]</sup>	SOT54	SC-43A	TO-92	PDTA123YS
PDTC123YT	SOT23	-	TO-236AB	PDTA123YT
PDTC123YU	SOT323	SC-70	-	PDTA123YU

[1] Also available in SOT54A and SOT54 variant packages (see [Section 2](#)).

### 1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

### 1.3 Applications

- General-purpose switching and amplification
- Inverter and interface circuits
- Circuit drivers

### 1.4 Quick reference data

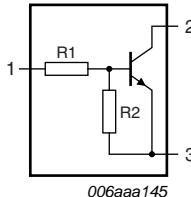
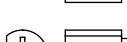
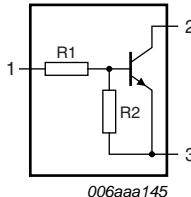
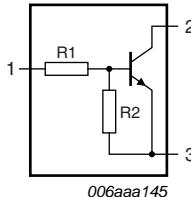
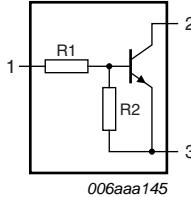
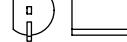
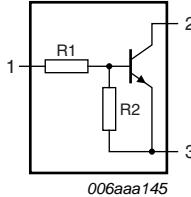
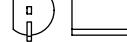
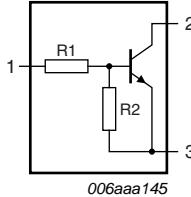
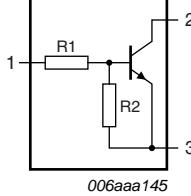
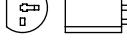
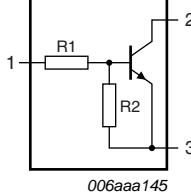
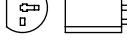
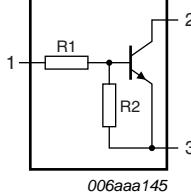
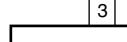
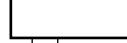
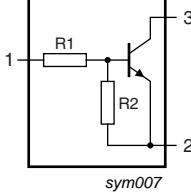
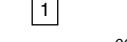
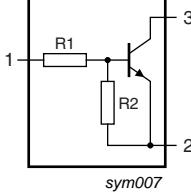
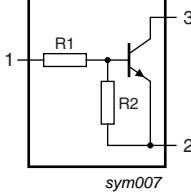
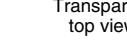
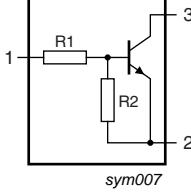
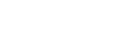
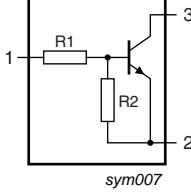
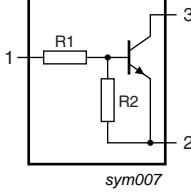
Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	50	V
I <sub>O</sub>	output current (DC)		-	-	100	mA
R <sub>1</sub>	bias resistor 1 (input)		1.54	2.2	2.86	kΩ
R <sub>2/R<sub>1</sub></sub>	bias resistor ratio		3.6	4.5	5.5	



## 2. Pinning information

**Table 3. Pinning**

Pin	Description	Simplified outline	Symbol
<b>SOT54</b>			
1	input (base)		
2	output (collector)	 	
3	GND (emitter)	  001aab347	 006aaa145
<b>SOT54A</b>			
1	input (base)		
2	output (collector)	 	
3	GND (emitter)	  001aab348	 006aaa145
<b>SOT54 variant</b>			
1	input (base)		
2	output (collector)	 	
3	GND (emitter)	  001aab447	 006aaa145
<b>SOT23; SOT323; SOT346; SOT416</b>			
1	input (base)	  	
2	GND (emitter)	  	
3	output (collector)	  006aaa144	 sym007
<b>SOT883</b>			
1	input (base)	  	
2	GND (emitter)	  	 Transparent top view
3	output (collector)	  sym007	 sym007

### 3. Ordering information

**Table 4. Ordering information**

Type number	Package			Version
	Name	Description		
PDTC123YE	SC-75	plastic surface mounted package; 3 leads		SOT416
PDTC123YK	SC-59A	plastic surface mounted package; 3 leads		SOT346
PDTC123YM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm		SOT883
PDTC123YS <sup>[1]</sup>	SC-43A	plastic single-ended leaded (through hole) package; 3 leads		SOT54
PDTC123YT	-	plastic surface mounted package; 3 leads		SOT23
PDTC123YU	SC-70	plastic surface mounted package; 3 leads		SOT323

[1] Also available in SOT54A and SOT54 variant packages (see [Section 2](#) and [Section 9](#)).

### 4. Marking

**Table 5. Marking codes**

Type number	Marking code <sup>[1]</sup>
PDTC123YE	19
PDTC123YK	31
PDTC123YM	G7
PDTC123YS	TC123Y
PDTC123YT	*AL
PDTC123YU	*19

[1] \* = -: made in Hong Kong  
 \* = p: made in Hong Kong  
 \* = t: made in Malaysia  
 \* = W: made in China

## 5. Limiting values

**Table 6. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	5	V
V <sub>I</sub>	input voltage				
	positive		-	+12	V
	negative		-	-5	V
I <sub>O</sub>	output current (DC)		-	100	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1ms	-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C			
	SOT416	[1]	-	150	mW
	SOT346	[1]	-	250	mW
	SOT883	[2][3]	-	250	mW
	SOT54	[1]	-	500	mW
	SOT23	[1]	-	250	mW
	SOT323	[1]	-	200	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 60 µm copper strip line, standard footprint.

## 6. Thermal characteristics

**Table 7. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air				
	SOT416	[1]	-	-	833	K/W
	SOT346	[1]	-	-	500	K/W
	SOT883	[2][3]	-	-	500	K/W
	SOT54	[1]	-	-	250	K/W
	SOT23	[1]	-	-	500	K/W
	SOT323	[1]	-	-	625	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

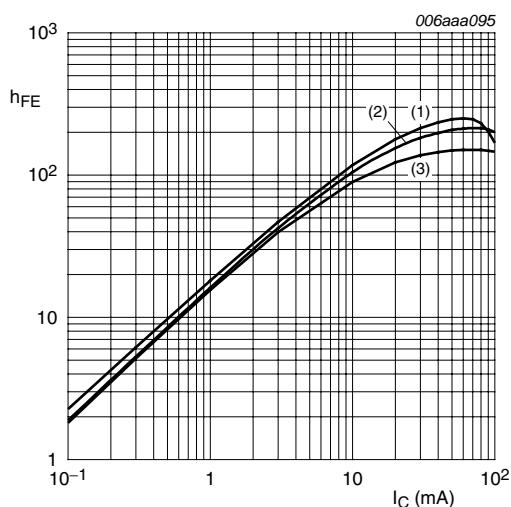
[3] Device mounted on an FR4 PCB with 60 µm copper strip line, standard footprint.

## 7. Characteristics

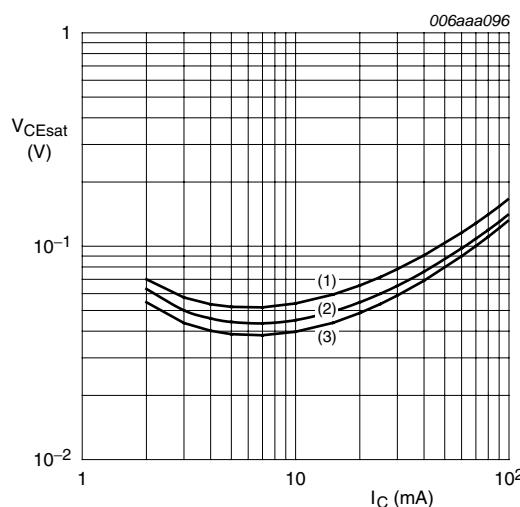
**Table 8. Characteristics**

$T_{amb} = 25^\circ\text{C}$  unless otherwise specified.

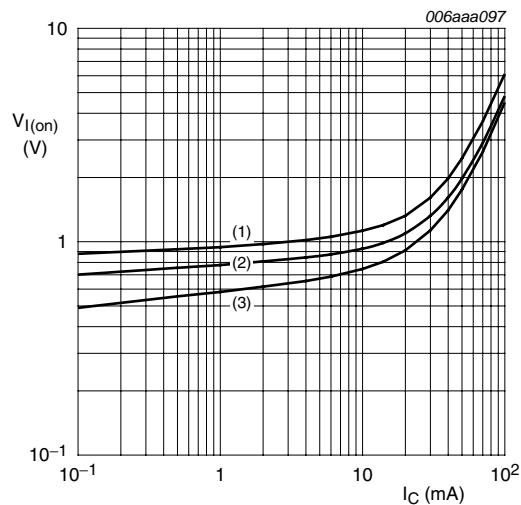
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{CBO}$	collector-base cut-off current	$V_{CB} = 50\text{ V}; I_E = 0\text{ A}$	-	-	100	nA
$I_{CEO}$	collector-emitter cut-off current	$V_{CE} = 30\text{ V}; I_B = 0\text{ A}$	-	-	1	μA
		$V_{CE} = 30\text{ V}; I_B = 0\text{ A}; T_j = 150^\circ\text{C}$	-	-	50	μA
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = 5\text{ V}; I_C = 0\text{ A}$	-	-	700	μA
$h_{FE}$	DC current gain	$V_{CE} = 5\text{ V}; I_C = 5\text{ mA}$	35	-	-	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 10\text{ mA}; I_B = 0.5\text{ mA}$	-	-	150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5\text{ V}; I_C = 100\text{ μA}$	-	0.75	0.3	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = 300\text{ mV}; I_C = 20\text{ mA}$	2.5	1.15	-	V
R1	bias resistor 1 (input)		1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio		3.6	4.5	5.5	
$C_c$	collector capacitance	$V_{CB} = 10\text{ V}; I_E = i_e = 0\text{ A}; f = 1\text{ MHz}$	-	-	2	pF



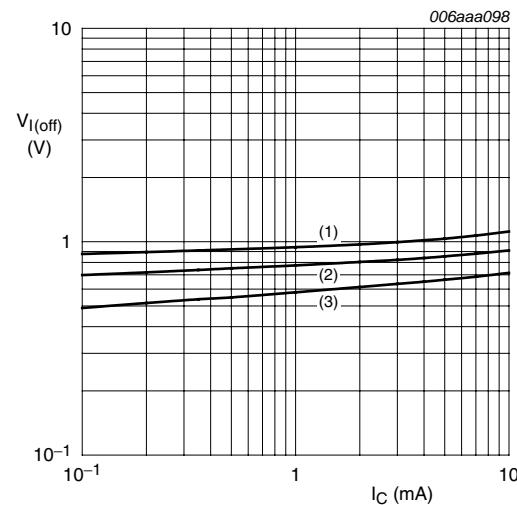
**Fig 1.** DC current gain as a function of collector current; typical values



**Fig 2.** Collector-emitter saturation voltage as a function of collector current; typical values



**Fig 3.** On-state input voltage as a function of collector current; typical values



**Fig 4.** Off-state input voltage as a function of collector current; typical values

## 8. Package outline

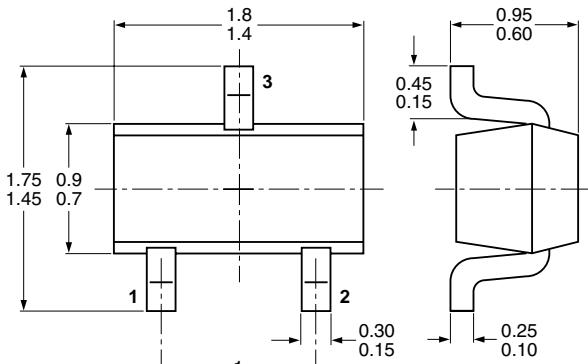


Fig 5. Package outline SOT416 (SC-75)

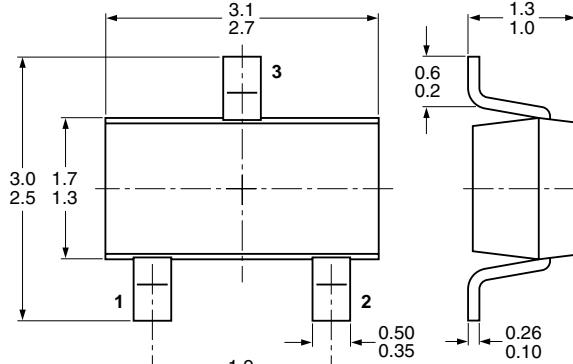


Fig 6. Package outline SOT346 (SC-59A/TO-236)

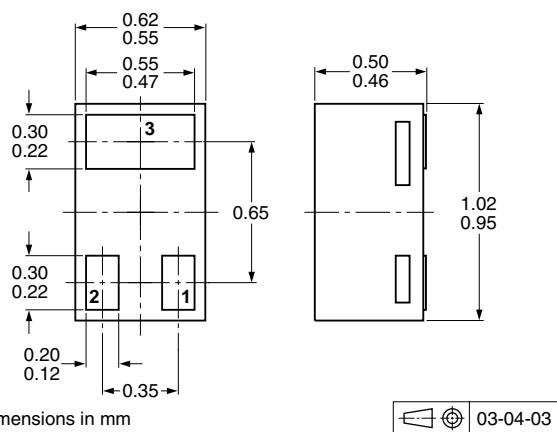


Fig 7. Package outline SOT883 (SC-101)

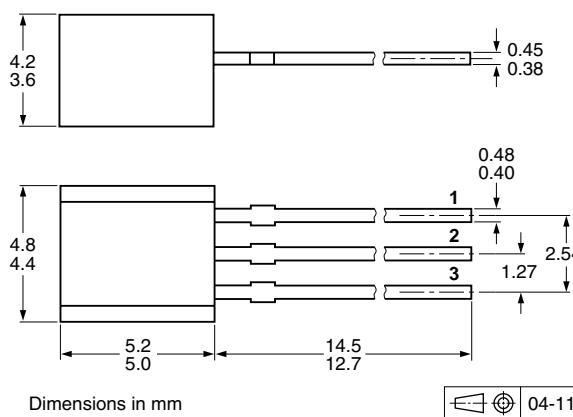


Fig 8. Package outline SOT54 (SC-43A/TO-92)

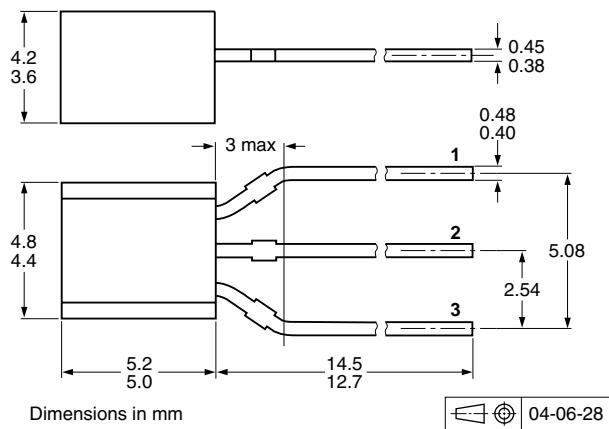


Fig 9. Package outline SOT54A

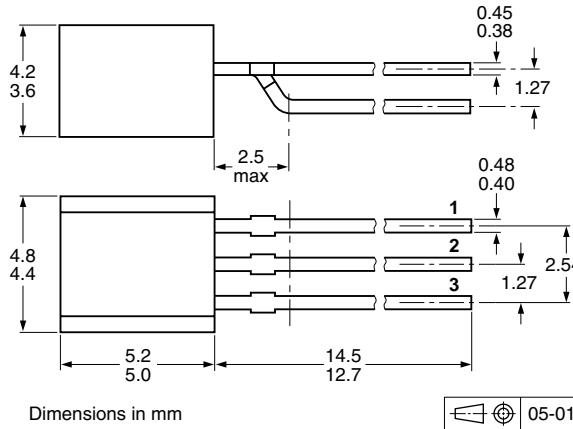
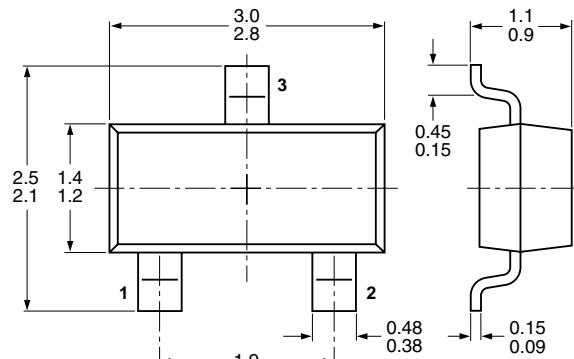
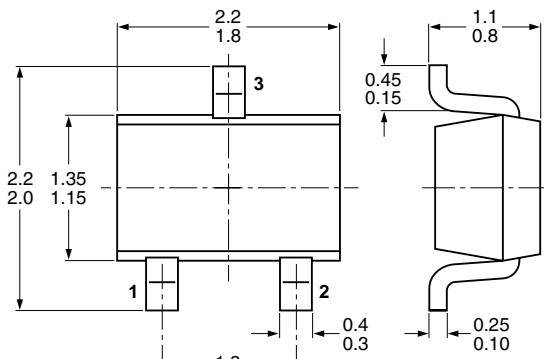


Fig 10. Package outline SOT54 variant



Dimensions in mm

04-11-04



Dimensions in mm

04-11-04

Fig 11. Package outline SOT23 (TO-236AB)

Fig 12. Package outline SOT323 (SC-70)

## 9. Packing information

**Table 9. Packing methods**The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

Type number	Package	Description	Packing quantity		
			3000	5000	10000
PDTC123YE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTC123YK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTC123YM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315
PDTC123YS	SOT54	bulk, straight leads	-	-412	-
	SOT54A	tape and reel, wide pitch	-	-	-116
		tape ammopack, wide pitch	-	-	-126
	SOT54 variant	bulk, delta pinning	-	-112	-
PDTC123YT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235
PDTC123YU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135

[1] For further information and the availability of packing methods, see [Section 12](#).